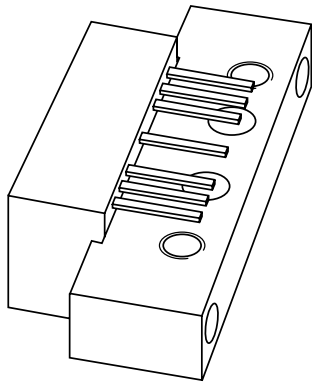


DATA SHEET



BGD906; BGD906MI 860 MHz, 21.5 dB gain power doubler amplifier

Product specification
Supersedes data of 2000 Mar 28

2001 Nov 01

860 MHz, 21.5 dB gain power doubler amplifier BGD906; BGD906MI

FEATURES

- Excellent linearity
- Extremely low noise
- Excellent return loss properties
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

APPLICATIONS

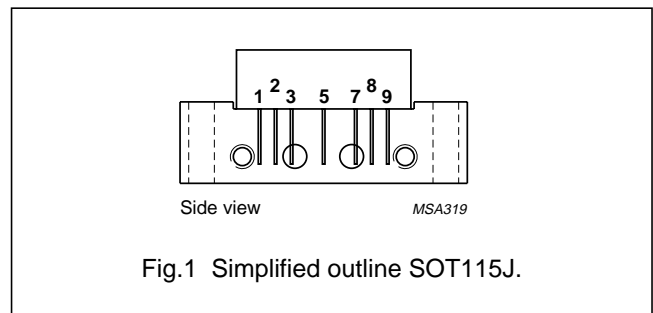
- CATV systems operating in the 40 to 900 MHz frequency range.

DESCRIPTION

Hybrid amplifier modules in a SOT115J package operating with a voltage supply of 24 V (DC). Both modules are electrically identical, only the pinning is different.

PINNING - SOT115J

PIN	DESCRIPTION	
	BGD906	BGD906MI
1	input	output
2, 3	common	common
5	+V _B	+V _B
7, 8	common	common
9	output	input



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	21.2	21.8	dB
		f = 900 MHz	22	23	dB
I _{tot}	total current consumption (DC)	V _B = 24 V; T _{mb} = 35 °C	405	435	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _B	supply voltage	–	30	V
V _i	RF input voltage	–	70	dBmV
T _{stg}	storage temperature	–40	+100	°C
T _{mb}	operating mounting base temperature	–20	+100	°C

860 MHz, 21.5 dB gain power doubler amplifier

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CHARACTERISTICSBandwidth 40 to 900 MHz; $V_B = 24$ V; $T_{mb} = 35$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _p	power gain	f = 50 MHz	21.2	21.5	21.8	dB
		f = 900 MHz	22	22.5	23	dB
SL	slope straight line	f = 40 to 900 MHz	0.5	1	1.5	dB
FL	flatness straight line	f = 40 to 900 MHz	–	–	±0.35	dB
S ₁₁	input return losses	f = 40 to 80 MHz	22	25	–	dB
		f = 80 to 160 MHz	21	24	–	dB
		f = 160 to 320 MHz	18	23	–	dB
		f = 320 to 550 MHz	17	23	–	dB
		f = 550 to 900 MHz	16	20	–	dB
S ₂₂	output return losses	f = 40 to 80 MHz	22	25	–	dB
		f = 80 to 160 MHz	21	25	–	dB
		f = 160 to 320 MHz	20	23	–	dB
		f = 320 to 550 MHz	19	22	–	dB
		f = 550 to 650 MHz	18	24	–	dB
		f = 650 to 750 MHz	17	23	–	dB
		f = 750 to 900 MHz	16	21	–	dB
S ₂₁	phase response	f = 50 MHz	–45	–	+45	deg
CTB	composite triple beat	49 chs flat; V _o = 47 dBmV; f _m = 859.25 MHz	–	–68.5	–66	dB
		77 chs flat; V _o = 44 dBmV; f _m = 547.25 MHz	–	–70	–67	dB
		110 chs flat; V _o = 44 dBmV; f _m = 745.25 MHz	–	–63	–61	dB
		129 chs flat; V _o = 44 dBmV; f _m = 859.25 MHz	–	–59	–57	dB
		110 chs; f _m = 397.25 MHz; V _o = 49 dBmV at 550 MHz; note 1	–	–62.5	–60.5	dB
		129 chs; f _m = 697.25 MHz; V _o = 49.5 dBmV at 860 MHz; note 2	–	–57	–54.5	dB
X _{mod}	cross modulation	49 chs flat; V _o = 47 dBmV; f _m = 55.25 MHz	–	–64	–62	dB
		77 chs flat; V _o = 44 dBmV; f _m = 55.25 MHz	–	–67.5	–65	dB
		110 chs flat; V _o = 44 dBmV; f _m = 55.25 MHz	–	–64	–61.5	dB
		129 chs flat; V _o = 44 dBmV; f _m = 55.25 MHz	–	–61	–60	dB
		110 chs; f _m = 397.25 MHz; V _o = 49 dBmV at 550 MHz; note 1	–	–60	–58	dB
		129 chs; f _m = 859.25 MHz; V _o = 49.5 dBmV at 860 MHz; note 2	–	–56.5	–55	dB

860 MHz, 21.5 dB gain power doubler amplifier

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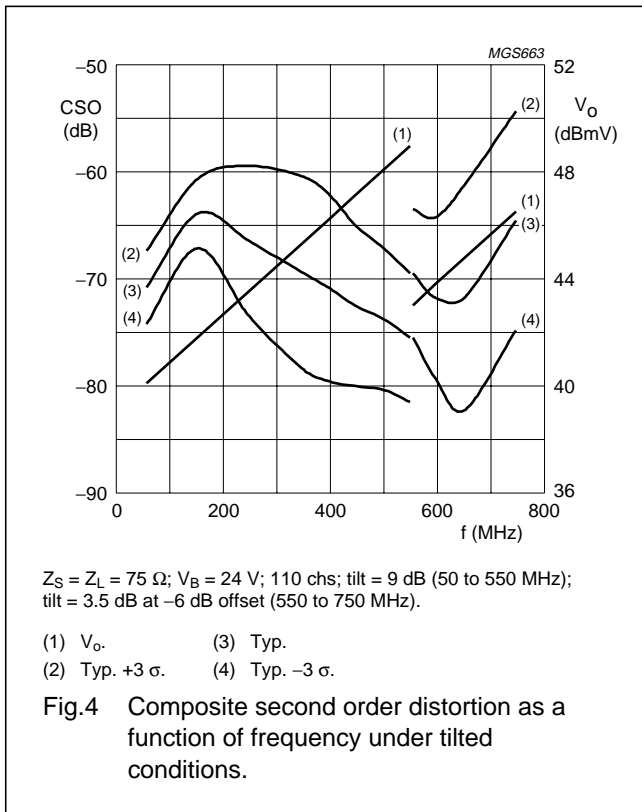
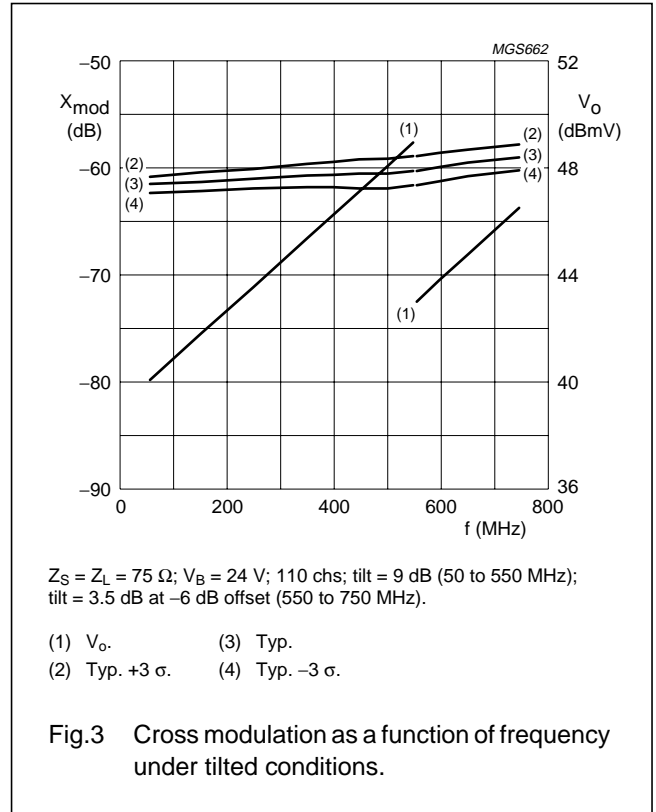
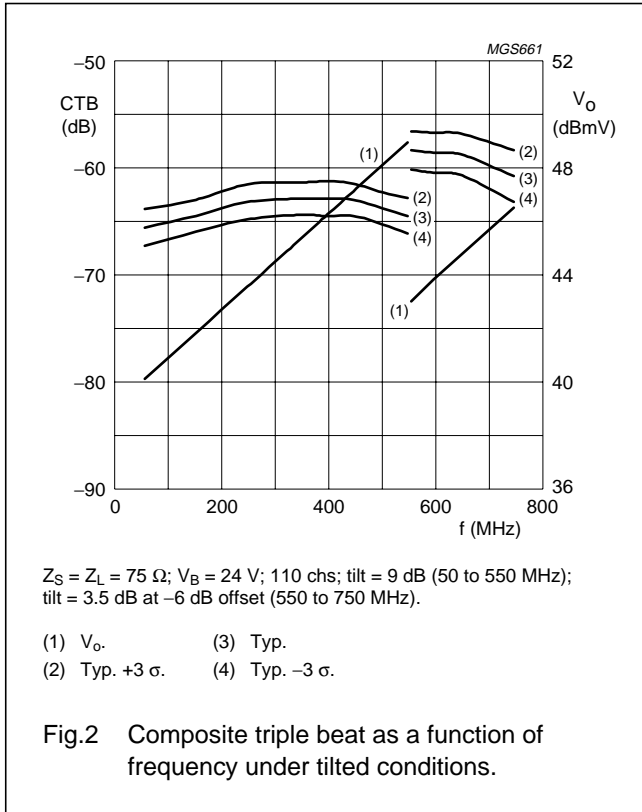
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CSO	composite second order distortion	49 chs flat; $V_o = 47$ dBmV; $f_m = 860.5$ MHz	–	–63	–59	dB
		77 chs flat; $V_o = 44$ dBmV; $f_m = 548.5$ MHz	–	–74	–65	dB
		110 chs flat; $V_o = 44$ dBmV; $f_m = 746.5$ MHz	–	–66	–58	dB
		129 chs flat; $V_o = 44$ dBmV; $f_m = 860.5$ MHz	–	–59	–54	dB
		110 chs; $f_m = 150$ MHz; $V_o = 49$ dBmV at 550 MHz; note 1	–	–64	–60	dB
		129 chs; $f_m = 150$ MHz; $V_o = 49.5$ dBmV at 860 MHz; note 2	–	–60	–54	dB
d_2	second order distortion	note 3	–	–83	–70	dB
		note 4	–	–81.5	–73	dB
		note 5	–	–79	–76	dB
V_o	output voltage	$d_{im} = -60$ dB; note 6	63.5	64.5	–	dBmV
		$d_{im} = -60$ dB; note 7	64.5	66.5	–	dBmV
		$d_{im} = -60$ dB; note 8	66.5	69	–	dBmV
		CTB compression = 1 dB; 129 chs flat; $f = 859.25$ MHz	48.5	49	–	dBmV
		CSO compression = 1 dB; 129 chs flat; $f = 860.5$ MHz	51	54	–	dBmV
NF	noise figure	$f = 50$ MHz	–	5	5.5	dB
		$f = 550$ MHz	–	4.5	5	dB
		$f = 750$ MHz	–	5	6	dB
		$f = 900$ MHz	–	6	7.5	dB
I_{tot}	total current consumption (DC)	note 9	405	420	435	mA

Notes

- Tilt = 9 dB (50 to 550 MHz)
tilt = 3.5 dB at –6 dB offset (550 to 750 MHz).
- Tilt = 12.5 dB (50 to 860 MHz).
- $f_p = 55.25$ MHz; $V_p = 44$ dBmV;
 $f_q = 805.25$ MHz; $V_q = 44$ dBmV;
measured at $f_p + f_q = 860.5$ MHz.
- $f_p = 55.25$ MHz; $V_p = 44$ dBmV;
 $f_q = 691.25$ MHz; $V_q = 44$ dBmV;
measured at $f_p + f_q = 746.5$ MHz.
- $f_p = 55.25$ MHz; $V_p = 44$ dBmV;
 $f_q = 493.25$ MHz; $V_q = 44$ dBmV;
measured at $f_p + f_q = 548.5$ MHz.
- Measured according to DIN45004B:
 $f_p = 851.25$ MHz; $V_p = V_o$;
 $f_q = 858.25$ MHz; $V_q = V_o - 6$ dB;
 $f_r = 860.25$ MHz; $V_r = V_o - 6$ dB;
measured at $f_p + f_q - f_r = 849.25$ MHz.
- Measured according to DIN45004B:
 $f_p = 740.25$ MHz; $V_p = V_o$;
 $f_q = 747.25$ MHz; $V_q = V_o - 6$ dB;
 $f_r = 749.25$ MHz; $V_r = V_o - 6$ dB;
measured at $f_p + f_q - f_r = 738.25$ MHz.
- Measured according to DIN45004B:
 $f_p = 540.25$ MHz; $V_p = V_o$;
 $f_q = 547.25$ MHz; $V_q = V_o - 6$ dB;
 $f_r = 549.25$ MHz; $V_r = V_o - 6$ dB;
measured at $f_p + f_q - f_r = 538.25$ MHz.
- The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 35 V.

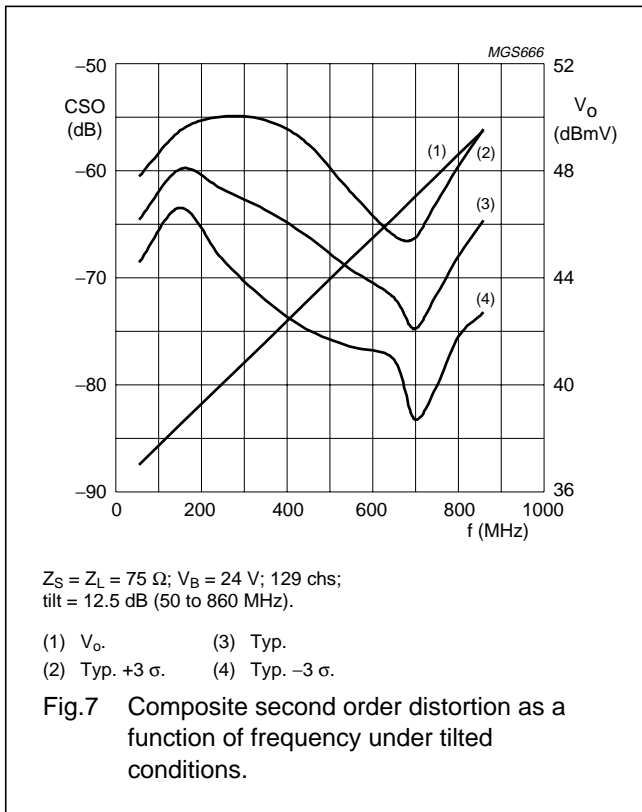
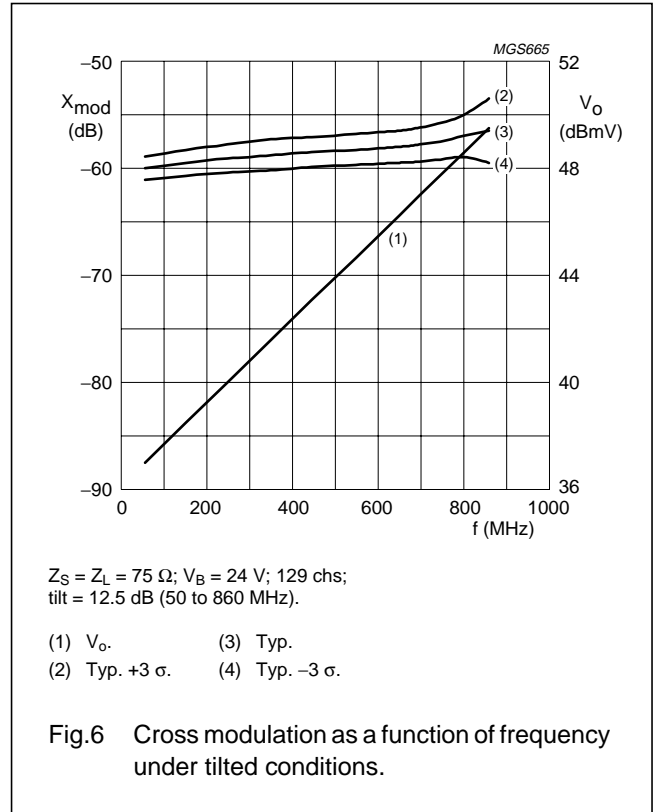
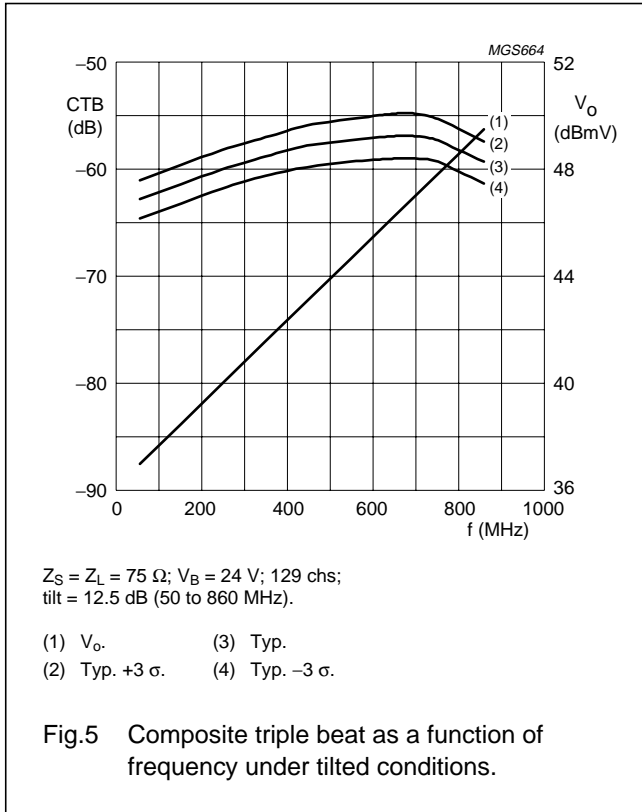
860 MHz, 21.5 dB gain power doubler amplifier

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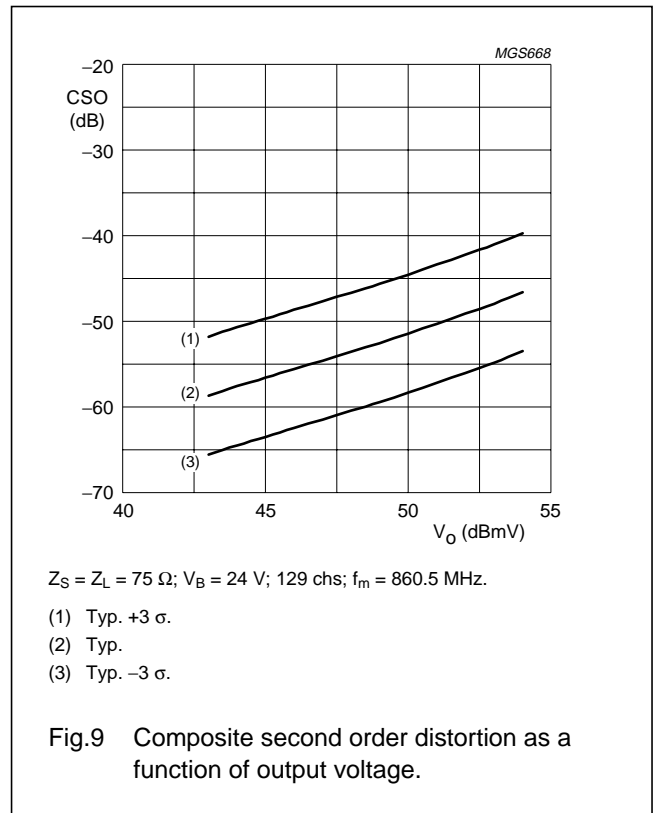
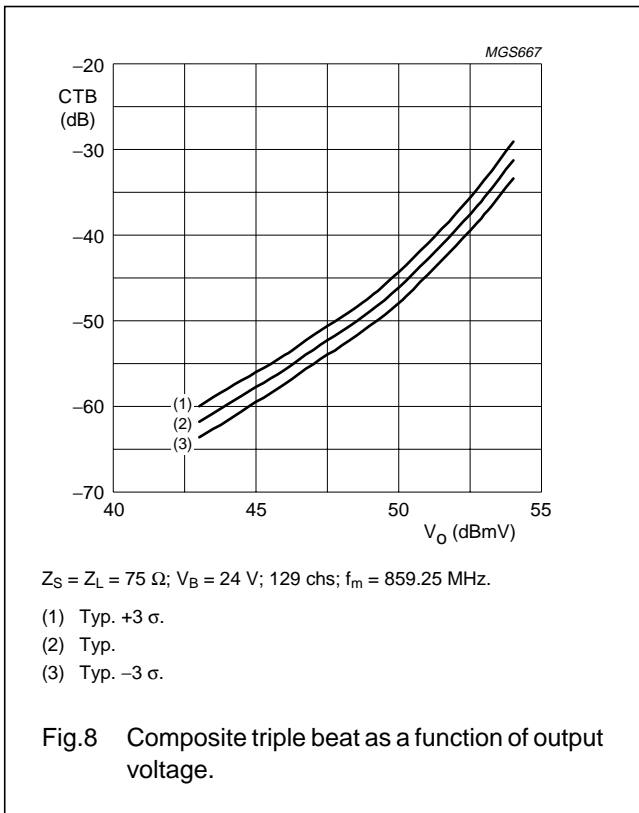
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860 MHz, 21.5 dB gain power doubler amplifier

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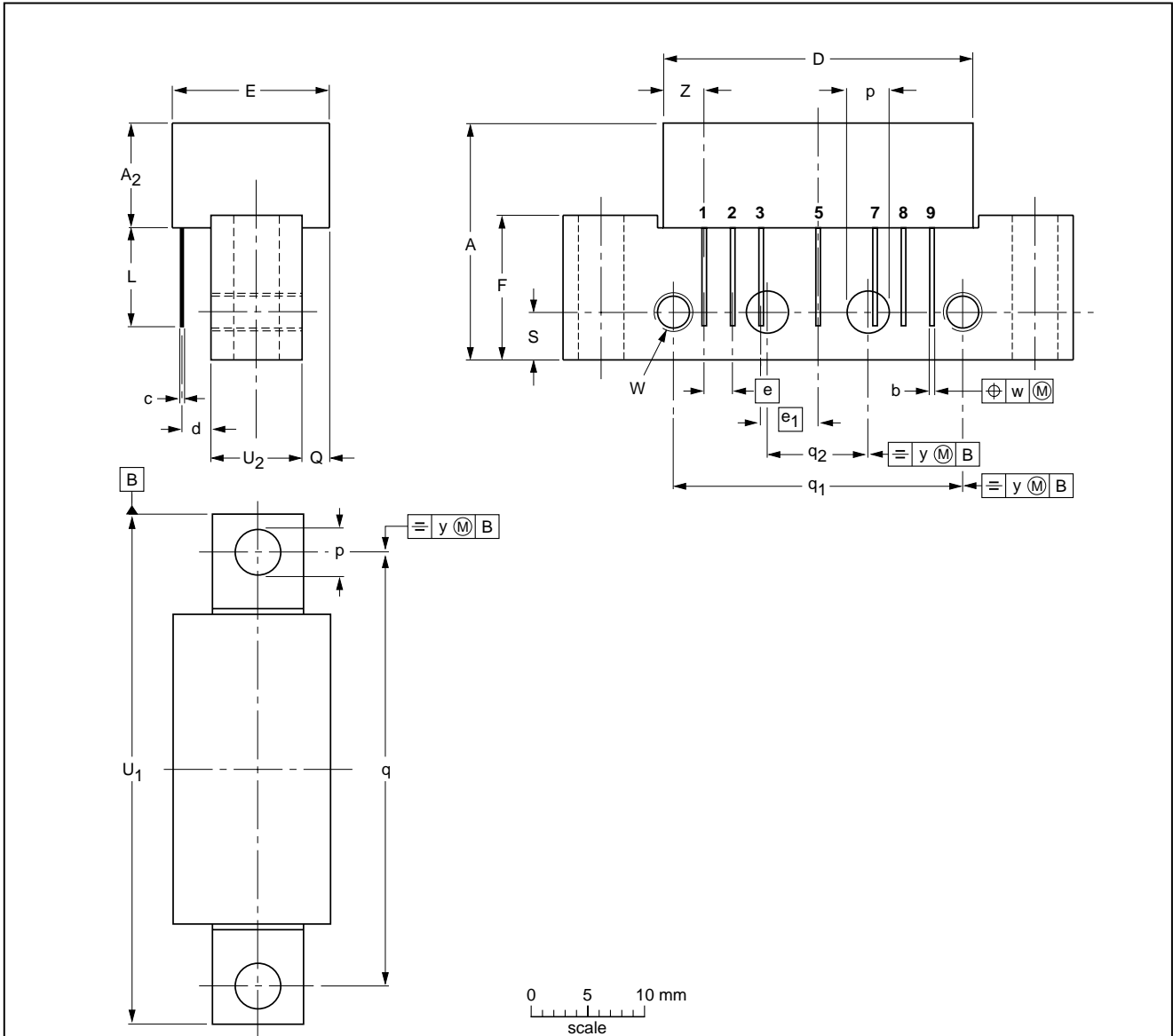
860 MHz, 21.5 dB gain power doubler amplifier

BGD906; BGD906MI

PACKAGE OUTLINE

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₂ max.	b	c	D max.	d max.	E max.	e	e ₁	F	L min.	p	Q max.	q	q ₁	q ₂	S	U ₁ max.	U ₂	W	w	y	Z max.
mm	20.8	9.1	0.51 0.38	0.25	27.2	2.54	13.75	2.54	5.08	12.7	8.8	4.15 3.85	2.4	38.1	25.4	10.2	4.2	44.75	8	6-32 UNC	0.25	0.1	3.8

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT115J						99-02-06

860 MHz, 21.5 dB gain power doubler amplifier

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NOTES

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NOTES

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